

Features

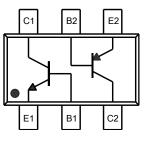
- Epitaxial Die Construction
- Two Internally Isolated NPN/PNP Transistors in One Package
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>BC847PNQ</u>)

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.006 grams (Approximate)



Top View



Device Schematic Top View

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BC847PN-7-F	AEC-Q101	K7P	7	8	3,000
BC847PN-13-F	AEC-Q101	K7P	13	8	10,000
BC847PN-7R-F	AEC-Q101	K7P	7	8	3,000

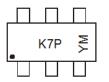
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} \mathsf{K7P} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex: D} = 2016) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex: 9} = \mathsf{September}) \end{array}$

Date Code Key

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Year	2015	201	6	2017	20	018	2019	2	2020	2021		2022
Code	С	D		E		F	G		Н	I		J
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings: NPN, BC847B Type (Q₁) (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	lc	100	mA
Peak Collector Current	I _{CM}	200	mA
Peak Emitter Current	I _{EM}	200	mA

Absolute Maximum Ratings: PNP, BC857B Type (Q₂) (@T_A = +25°C, unless otherwise specified.)

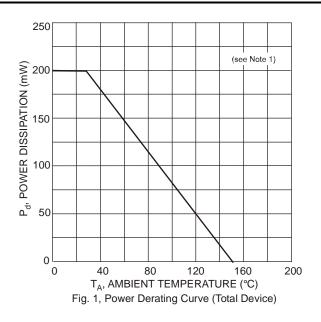
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-6	V
Collector Current	Ic	-100	mA
Peak Collector Current	ICM	-200	mA
Peak Emitter Current	I _{EM}	-200	mA

Thermal Characteristics – Total Device (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Total Device	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-65 to +150	°C

Note: 5. For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR-4 PCB; the device is measured under still air conditions whilst operating in a steady-state.

Thermal Characteristics – Total Device



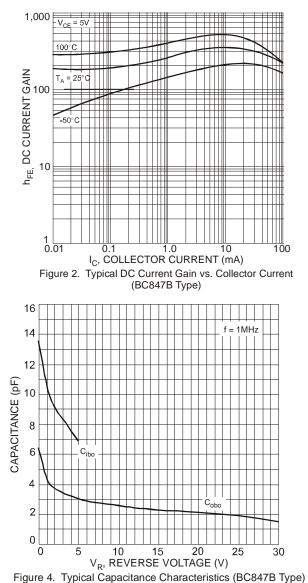


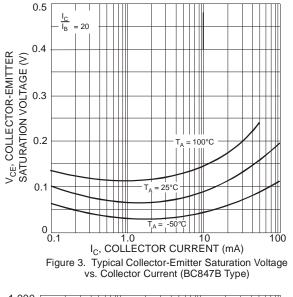
BC847PN

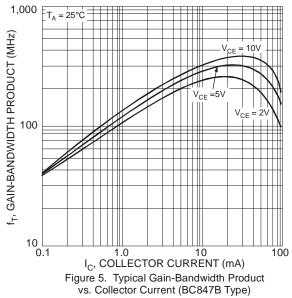
Electrical Characteristics: NPN, BC847B Type (Q1) (@TA = +25°C, unless otherwise specified.)

Characteristic (Note 6)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	_		V	$I_{\rm C} = 100 \mu A$
Collector-Emitter Breakdown Voltage	BV _{CEO}	45	—	_	V	$I_{C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	6	—	_	V	I _E = 100μA
DC Current Gain	h _{FE}	200	290	450	—	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		90 200	250 600	mV	$I_{C} = 10mA$, $I_{B} = 0.5mA$ $I_{C} = 100mA$, $I_{B} = 5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		700 900	—	mV	$I_{C} = 10mA, I_{B} = 0.5mA$ $I_{C} = 100mA, I_{B} = 5.0mA$
Base-Emitter Voltage	V _{BE(ON)}	580 —	660 —	700 720	mV	$V_{CE} = 5.0V, I_C = 2.0mA$ $V_{CE} = 5.0V, I_C = 10mA$
Collector-Cutoff Current	I _{CBO}			15 5.0	nA μA	$V_{CB} = 30V$ $V_{CB} = 30V, T_A = +150^{\circ}C$
Gain Bandwidth Product	f⊤	100	300	—	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 100MHz
Collector-Base Capacitance	C _{CBO}	_	3.5	6.0	pF	V _{CB} = 10V, f = 1.0MHz
Noise Figure	NF	_	2.0	10	dB	$V_{CE} = 5V, I_C = 200\mu A,$ $R_g = 2.0k\Omega, f = 1.0kHz,$ $\Delta f = 200Hz$

Note: 6. Short duration pulse test used to minimize self-heating effect.







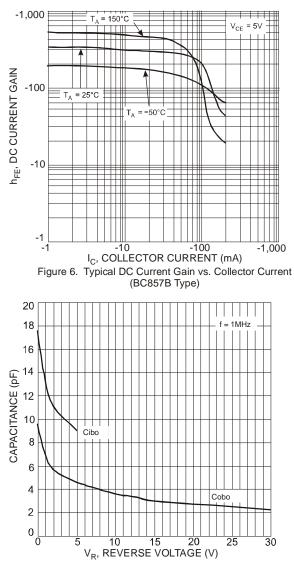


Electrical Characteristics: PNP, BC857B Type (Q₂) (@T_A = +25°C, unless otherwise specified.)

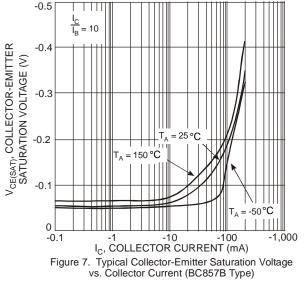
Characteristic (Note 7)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50		—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-45	_	—	V	$I_{C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	_	—	V	I _E = -100μA
DC Current Gain	h _{FE}	220	290	475	_	$V_{CE} = -5.0V, I_{C} = -2.0mA$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-75 -250	-300 -650	mV	$I_{C} = -10mA$, $I_{B} = -0.5mA$ $I_{C} = -100mA$, $I_{B} = -5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		-700 -850	 -950	mV	$I_{C} = -10mA$, $I_{B} = -0.5mA$ $I_{C} = -100mA$, $I_{B} = -5.0mA$
Base-Emitter Voltage	V _{BE(ON)}	-600 —	-650 —	-750 -820	mV	$V_{CE} = -5.0V, I_C = -2.0mA$ $V_{CE} = -5.0V, I_C = -10mA$
Collector-Cutoff Current	I _{СВО}		—	-15 -4.0	nA μA	V _{CB} = -30V V _{CB} = -30V, T _A = +150°C
Gain Bandwidth Product	fT	100	200	—	MHz	$V_{CE} = -5.0V, I_C = -10mA, f = 100MHz$
Collector-Base Capacitance	C _{CBO}	_	3	4.5	pF	$V_{CB} = -10V, f = 1.0MHz$
Noise Figure	NF	_	_	10	dB	$\label{eq:Vce} \begin{array}{l} V_{CE}=-5V,\ I_C=-200\mu A,\\ R_g=2.0k\Omega,\ f=1.0kHz,\\ \Delta f=200Hz \end{array}$

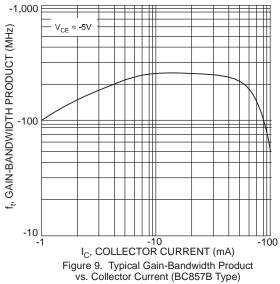
Note:

7. Short duration pulse test used to minimize self-heating effect.





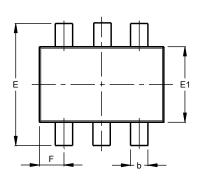


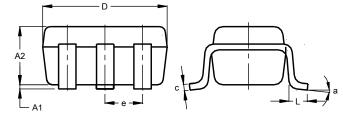




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

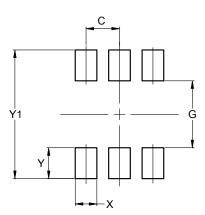




SOT363							
Dim	Min	Max	Tun				
		Wax	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
c	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 B	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	Dimen	sions	in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363

SOT363

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500

BC847PN Document number: DS30278 Rev. 14 - 2



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